μA777
Precision Operational Amplifier

FEATURES

- **Low offset voltage and offset current**
- **Low offset voltage and current drift**
- **Low input bias current**
- **Low input noise voltage**
- **Large common mode and differential voltage ranges**

ABSOLUTE MAXIMUM RATINGS

Supply Voltage ..... ±22V
Internal Power Dissipation (Note 1)
Metal Can 500mW
Differential Input Voltage ..... ±30V
Input Voltage (Note 2) ..... ±15V
Storage Temperature Range ..... −65°C to +150°C
Operating Temperature Range (HC) ..... 0°C to 70°C
(HM) .. −55°C to +125°C
Lead Temperature (Soldering, 10s) ..... 300°C
..... 260°C
Output Short Circuit Duration (Note 3) ..... Indefinite

Note 1: Rating applies to ambient temperatures up to 70°C. Above 70°C ambient derate linearly at 6.3mW/°C for Metal Can, 8.3mW/°C for the DIP, and 5.6mW/°C for the Mini DIP.

Note 2. For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

Note 3. Short Circuit may be to ground or either supply. Rating applies to +125°C case temperature or +75°C ambient temperature for $I_{SET} \leq 30\mu A$.

ORDERING INFORMATION

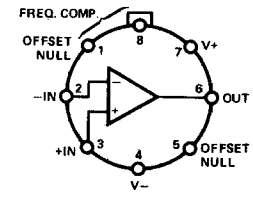
	Dice	TO-99 Can
μA777C μA777M	μA777C/D μA777M/D	μA777HC μA777MC

GENERAL DESCRIPTION

The μA777 is a monolithic Precision Operational Amplifier. It is an excellent choice when performance versus cost trade-offs are possible between super beta or FET input operational amplifiers and low cost general purpose operational amplifiers. Low offset and bias currents improve system accuracy when used in applications such as long term integrators, sample and hold circuits and high source impedance summing amplifiers. Even though the input bias current is extremely low, the μA777 maintains full ±30V differential voltage range. High common mode input voltage range, latch-up protection, short circuit protection and simple frequency compensation make the device versatile and easily used.

PIN CONFIGURATION

8-LEAD METAL CAN
(TOP VIEW)



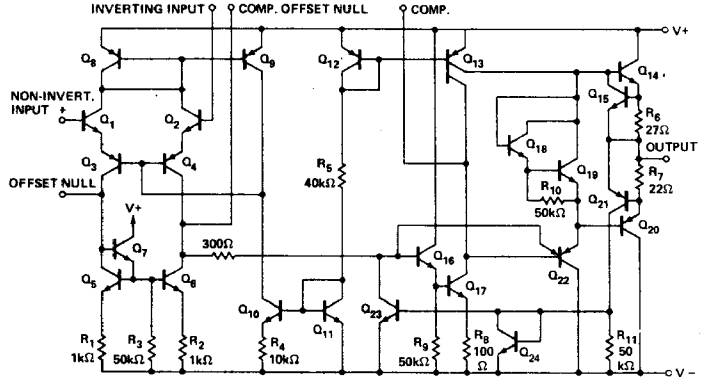
(outline dwg TY)

ELECTRICAL CHARACTERISTICS FOR μA777 (V_S = ±15V, T_A = 25°C, C_C = 30pF unless otherwise specified

PARAMETERS		CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage		$R_S \leq 50k\Omega$		0.7	5.0	mV
Input Offset Current				0.7	20.0	nA
Input Bias Current				25	100	nA
Input Resistance			1.0	2.0		MΩ
Input Capacitance				3.0		pF
Offset Voltage Adjustment Range				±25		mV
Large Signal Voltage Gain		$R_L \geq 2k\Omega$, V_{OUT} = ±10V	25,000	250,000		V/V
Output Resistance				100		Ω
Output Short Circuit Current				±25		mA
Supply Current				1.9	2.8	mA
Power Consumption				60	85	mW
Transient Response (Voltage Follower, Gain of 1)	Rise Time	V_{IN} = 20mV, C_C = 30pF R_L = 2kΩ, $C_L \leq$ 100pF		0.3		μs
	Overshoot			5.0		%
Slew Rate (Voltage Follower, Gain of 1)		$R_L \geq 2k\Omega$		0.5		V/μs
Transient Response (Voltage Follower, Gain of 10)	Rise Time	V_{IN} = 20mV, C_C = 3.5pF R_L = 2kΩ, $C_L \leq$ 100pF		0.3		μs
	Overshoot			5.0		%
Slew Rate (Voltage Follower, Gain of 10)		$R_L \leq 2k\Omega$, C_C = 3.5pF		5.5		V/μs
The following specifications apply over operating temperature range.						
Input Offset Voltage		$R_S \leq 50k\Omega$		0.8	5.0	mV
Average Input Offset Voltage Drift		$R_S \leq 50k\Omega$		4.0	30	μV/°C
Input Offset Current					40	nA
Average Input Offset Current Drift		25°C ≤ T_A ≤ +70°C 0°C ≤ T_A ≤ +25°C		0.01 0.02	10.3 0.6	nA/°C nA/°C
Input Bias Current					200	nA
Input Voltage Range			±12	±13		V
Common Mode Rejection Ratio		$R_S \leq 50k\Omega$	70	95		dB
Supply Voltage Rejection Ratio		$R_S \leq 50k\Omega$		15	150	μV/V
Large Signal Voltage Gain		$R_L \geq 2k\Omega$, V_{OUT} = ±10V	15,000			V/V
Output Voltage Swing		$R_L \geq 10k\Omega$	±12	±14		V
		$R_L \geq 2k\Omega$	±10	±13		V
Power Consumption				60	100	mW

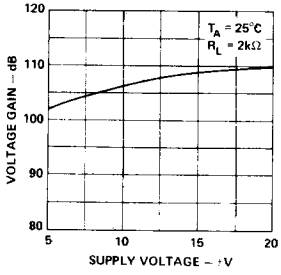
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EQUIVALENT CIRCUIT

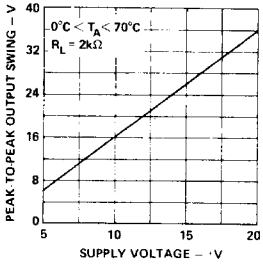


TYPICAL PERFORMANCE CURVES

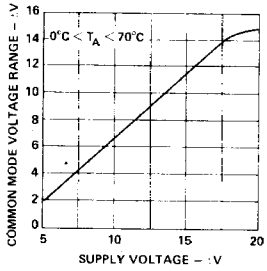
OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF SUPPLY VOLTAGE



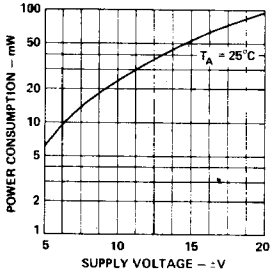
OUTPUT VOLTAGE SWING AS A FUNCTION OF SUPPLY VOLTAGE



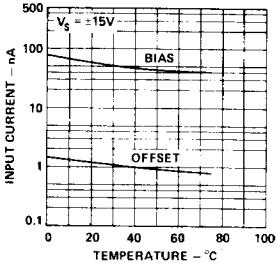
INPUT COMMON MODE VOLTAGE RANGE AS A FUNCTION OF SUPPLY VOLTAGE



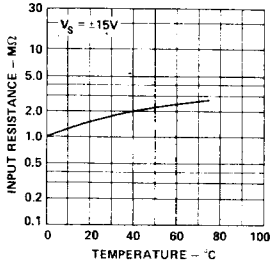
POWER CONSUMPTION AS A FUNCTION OF SUPPLY VOLTAGE



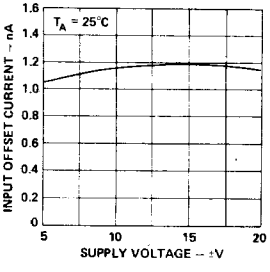
INPUT CURRENT AS A FUNCTION OF AMBIENT TEMPERATURE



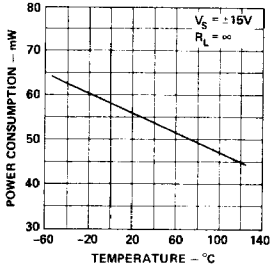
INPUT RESISTANCE AS A FUNCTION OF AMBIENT TEMPERATURE



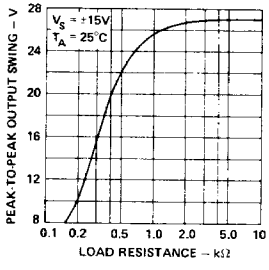
INPUT OFFSET CURRENT AS A FUNCTION OF SUPPLY VOLTAGE



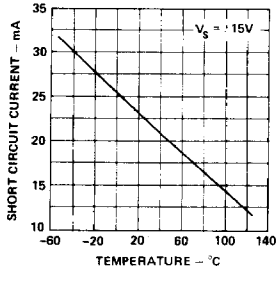
POWER CONSUMPTION AS A FUNCTION OF AMBIENT TEMPERATURE



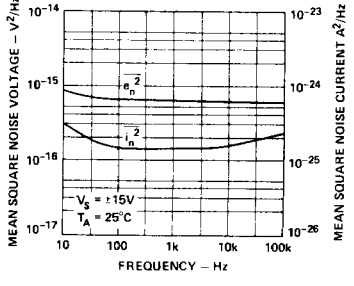
OUTPUT VOLTAGE SWING AS A FUNCTION OF LOAD RESISTANCE



OUTPUT SHORT-CIRCUIT CURRENT AS A FUNCTION OF AMBIENT TEMPERATURE

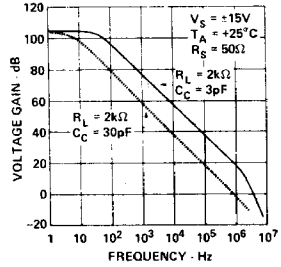


INPUT NOISE VOLTAGE AND CURRENT AS A FUNCTION OF FREQUENCY

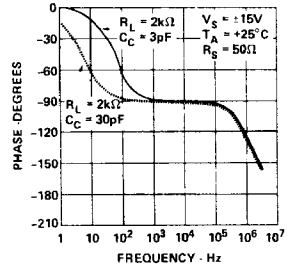


TYPICAL PERFORMANCE CURVES

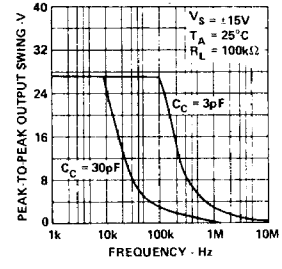
OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF FREQUENCY



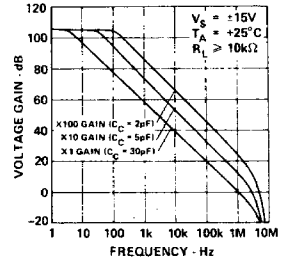
OPEN LOOP PHASE RESPONSE AS A FUNCTION OF FREQUENCY



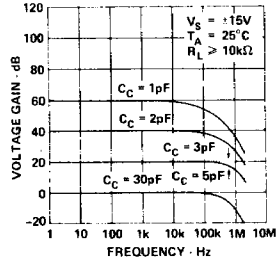
OUTPUT VOLTAGE SWING AS A FUNCTION OF FREQUENCY



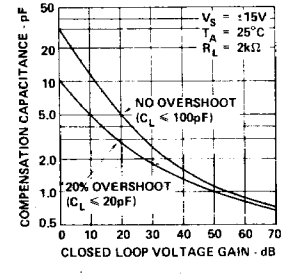
OPEN LOOP VOLTAGE GAIN AS A FUNCTION OF FREQUENCY FOR VARIOUS GAIN/COMPENSATION OPTIONS



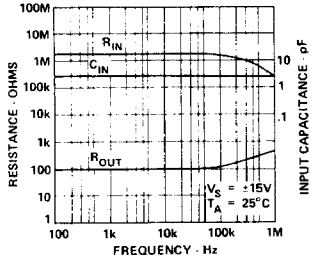
FREQUENCY RESPONSE FOR VARIOUS CLOSED-LOOP GAINS



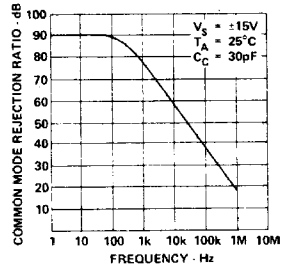
COMPENSATION CAPACITANCE AS A FUNCTION OF CLOSED LOOP VOLTAGE GAIN



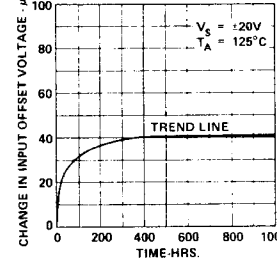
INPUT RESISTANCE, OUTPUT RESISTANCE, AND INPUT CAPACITANCE AS A FUNCTION OF FREQUENCY



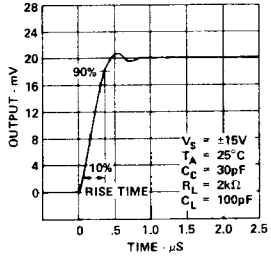
COMMON MODE REJECTION RATIO AS A FUNCTION OF FREQUENCY



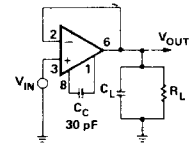
INPUT OFFSET VOLTAGE DRIFT AS A FUNCTION OF TIME



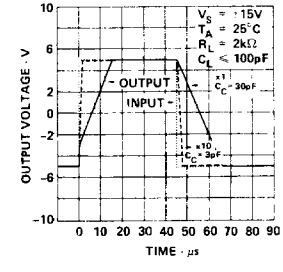
VOLTAGE FOLLOWER TRANSIENT RESPONSE (GAIN OF 1)



TRANSIENT RESPONSE TEST CIRCUIT

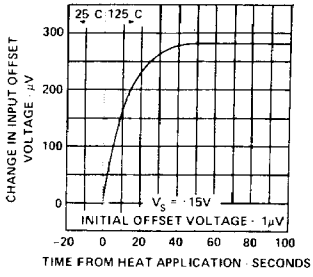


VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE

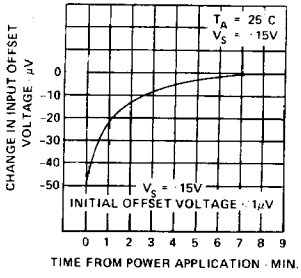


TYPICAL PERFORMANCE CURVES

THERMAL RESPONSE OF INPUT OFFSET VOLTAGE TO STEP CHANGE OF CASE TEMPERATURE

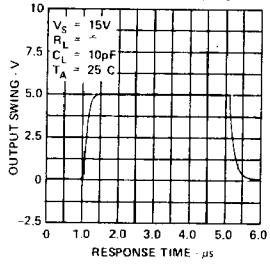


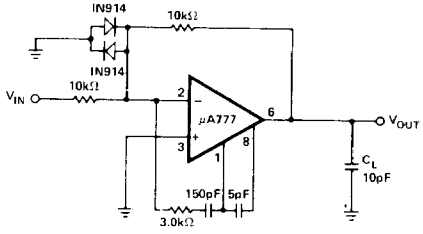
STABILIZATION TIME OF INPUT OFF—SET VOLTAGE FROM POWER TURN-ON



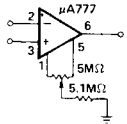
FEED FORWARD COMPENSATION

LARGE SIGNAL FEEDFORWARD TRANSIENT RESPONSE

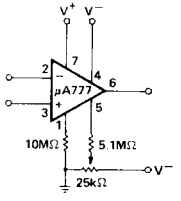




VOLTAGE OFFSET NULL CIRCUIT

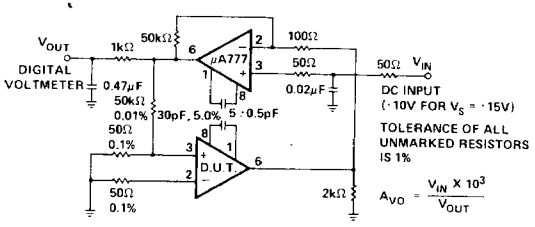


SUGGESTED



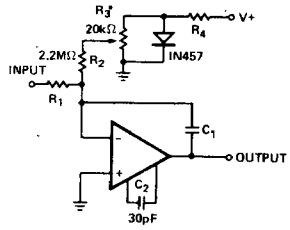
ALTERNATE

GAIN TEST CIRCUIT



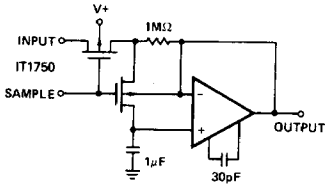
TYPICAL APPLICATIONS

BIAS COMPENSATED LONG TIME INTEGRATOR

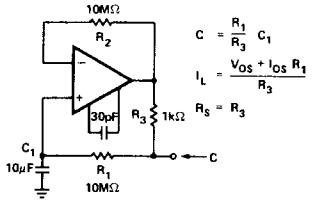


*ADJUST R_3 FOR MINIMUM INTEGRATOR DRIFT

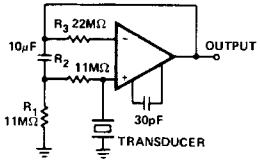
SAMPLE AND HOLD



CAPACITANCE MULTIPLIER

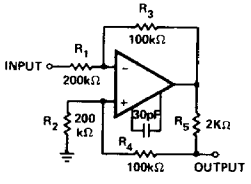


AMPLIFIER FOR CAPACITANCE TRANSDUCERS



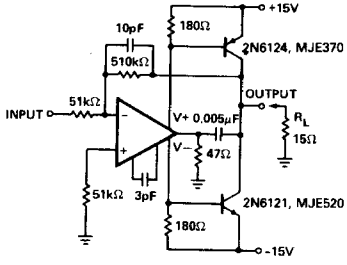
LOW FREQUENCY CUTOFF $R_1 \times C_1$

BILATERAL CURRENT SOURCE

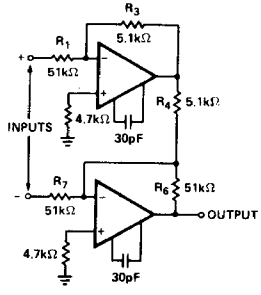


$$I_{OUT} = \frac{R_3 V_{IN}}{R_1 R_5} \; ; R_1 = R_2; R_3 = R_4 + R_5$$

HIGH SLEW RATE POWER AMPLIFIER



±100V COMMON MODE RANGE INSTRUMENTATION AMPLIFIER



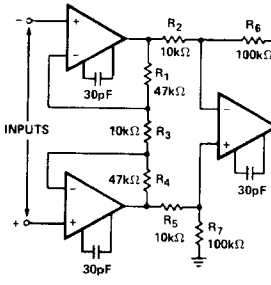
$$\frac{R_1}{R_7} \equiv \frac{R_3}{R_4} \text{ for best CMRR}$$

$R_3 = R_4$

$R_1 = R_6 = 10R_3$

$$\text{Gain} = \frac{R_7}{R_6}$$

INSTRUMENTATION AMPLIFIER WITH HIGH COMMON MODE REJECTION



$$\frac{R_2}{R_5} \equiv \frac{R_6}{R_7} \text{ for best CMRR}$$

$$\frac{R_1}{R_2} = \frac{R_4}{R_5}$$

$$\text{Gain} = \frac{R_6}{R_2}\left(1 + \frac{2R_1}{R_3}\right)$$

LifeElectronics
Живое партнерство

ООО «ЛайфЭлектроникс» **“LifeElectronics” LLC**

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- *Конкурентоспособные цены и скидки постоянным клиентам.*
- *Специальные условия для постоянных клиентов.*
- *Подбор аналогов.*
- *Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.*

- *Приемлемые сроки поставки, возможна ускоренная поставка.*
- *Доставку товара в любую точку России и стран СНГ.*
- *Комплексную поставку.*
- *Работу по проектам и поставку образцов.*
- *Формирование склада под заказчика.*

- *Сертификаты соответствия на поставляемую продукцию (по желанию клиента).*
- *Тестирование поставляемой продукции.*
- *Поставку компонентов, требующих военную и космическую приемку.*
- *Входной контроль качества.*
- *Наличие сертификата ISO.*

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- *Регистрацию проекта у производителя компонентов.*
- *Техническую поддержку проекта.*
- *Защиту от снятия компонента с производства.*
- *Оценку стоимости проекта по компонентам.*
- *Изготовление тестовой платы монтаж и пусконаладочные работы.*

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